

# CALICE simulation results

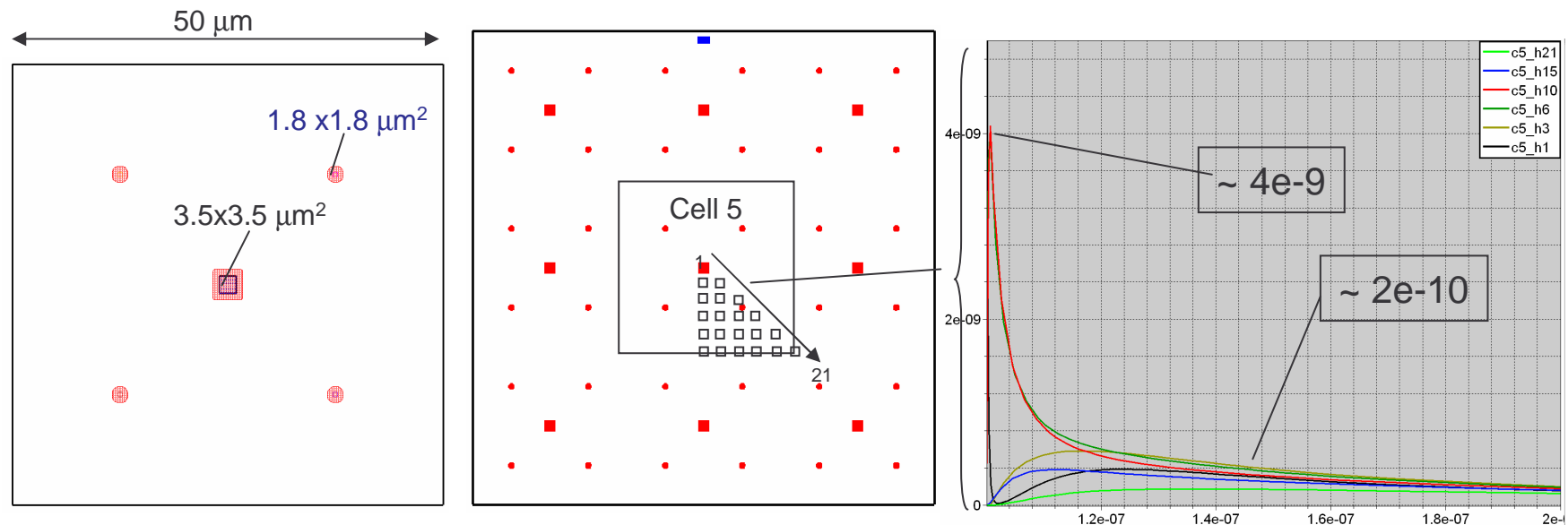
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Progress on CALICE MAPS detector simulations:

- S/N analysis for recent results
- Optimization: discussions & conclusions
- Conclusions

# CALICE simulation results

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Pixel layout

Transient  $I_d$

- 1.8 x 1.8 μm<sup>2</sup> diode size
- 21 hits simulated, 5 μm pitch
- 121 extrapolated hits / pixel
- 961 extrapolated hits / cell

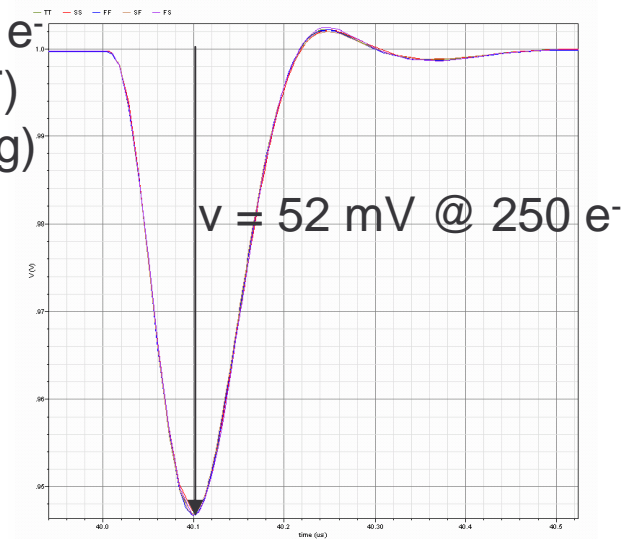
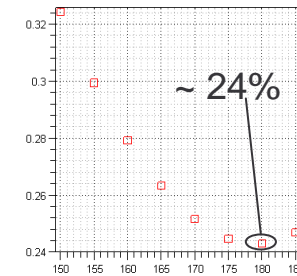
<u>Bias</u>	
• Diode	: 1.5V fixed
• Nwell	: 3.3V
• Pwell	: 0V
• Subs	: floating

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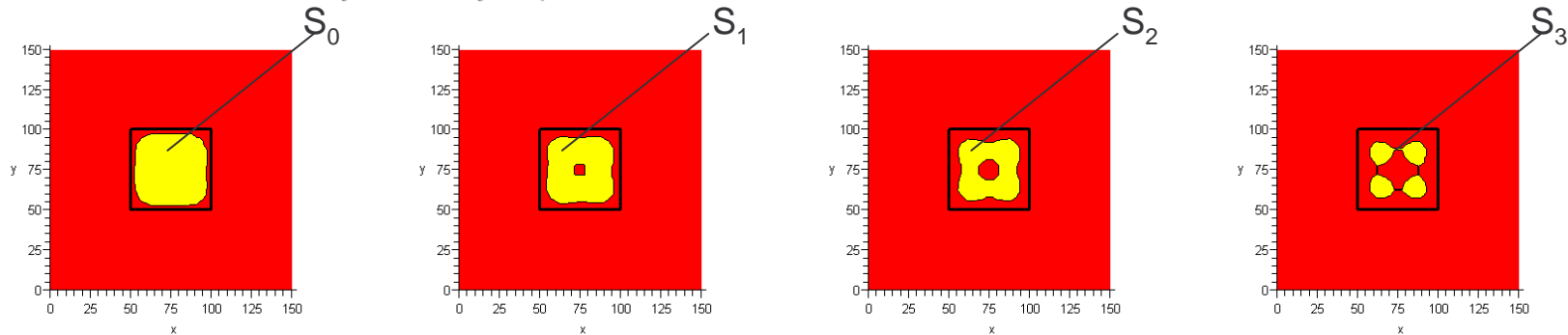
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- $v = 52 \text{ mV @ } 250 \text{ e}^-$
- Noise = 12 mV (8 fF)
- S/N = 4.33 (Sg = Ng)
- $e^-_{in} \sim 57 \text{ e}^-$



S/N @ 150 ns can be increased by increasing the threshold. This reduces the effective pixel area (however it could be 'recovered' by the n layers)



$Q_{thr} 225 \Rightarrow S/N \sim 4$

$Q_{thr} 250 \Rightarrow S/N \sim 4.4$

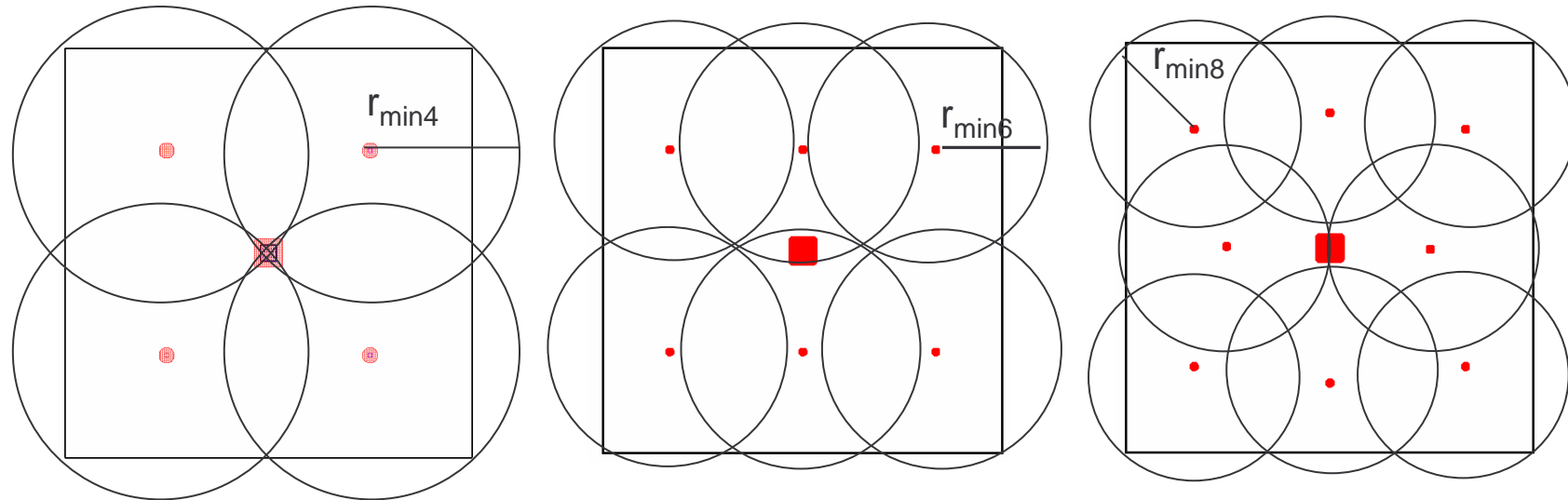
$Q_{thr} 275 \Rightarrow S/N \sim 4.8$

$Q_{thr} 300 \Rightarrow S/N \sim 5.2$

Simulations for 3.6 in progress. However, achieving a S/N exceeding 10 for a reasonable pixel size seems to be very difficult with the current layout

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4 diodes

6 diodes

8 diodes

## Layout optimization

- Improved diodes placement (minimum circle covering)
- The approach is to arrange the diodes within the square (pixel) to minimize the maximum distance from any point within the square to any collecting diode
- Solutions available for some tens of diodes

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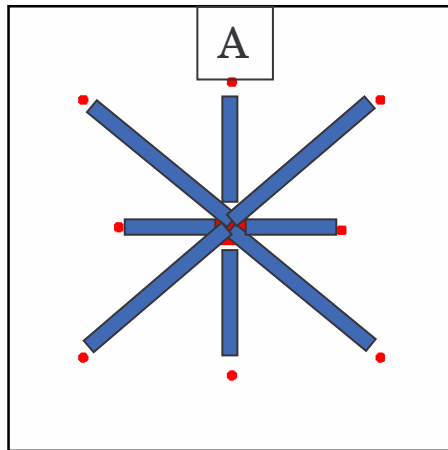
Nr <sub>diodes</sub> Size( $\mu$ )	4	6	8
0.9	2.54;17.2	3.81;14.55	5.08;12.55
1.8	10.17;16.75	15.26;14.1	20.35;12.1
3.6	40.7;15.87	61.06;13.2	81.41;11.2

**Collecting area ( $\mu^2$ ) and maximum collecting distance ( $\mu$ ) for 4,6,8 diodes layout**

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8 Diodes layout

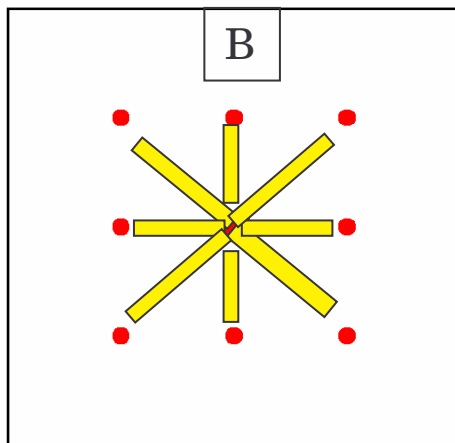


•  $\Sigma \text{ lengths} = 148.1$

$d_{\max} = 12.55$

$\Sigma \text{ lengths [A]} \sim 1.22 \Sigma \text{ lengths [A]}$

$d_{\max} \text{ [A]} \sim 0.7 d_{\max} \text{ [B]}$



•  $\Sigma \text{ lengths} = 120.71$

$d_{\max} = 12.5 * 2$

q 'B' better than 'A' for charge collection

q S/N : Noise [lengths] needed

$\Sigma \text{ lengths}$	4	6	8
0.9	70.7	108.3	148.1

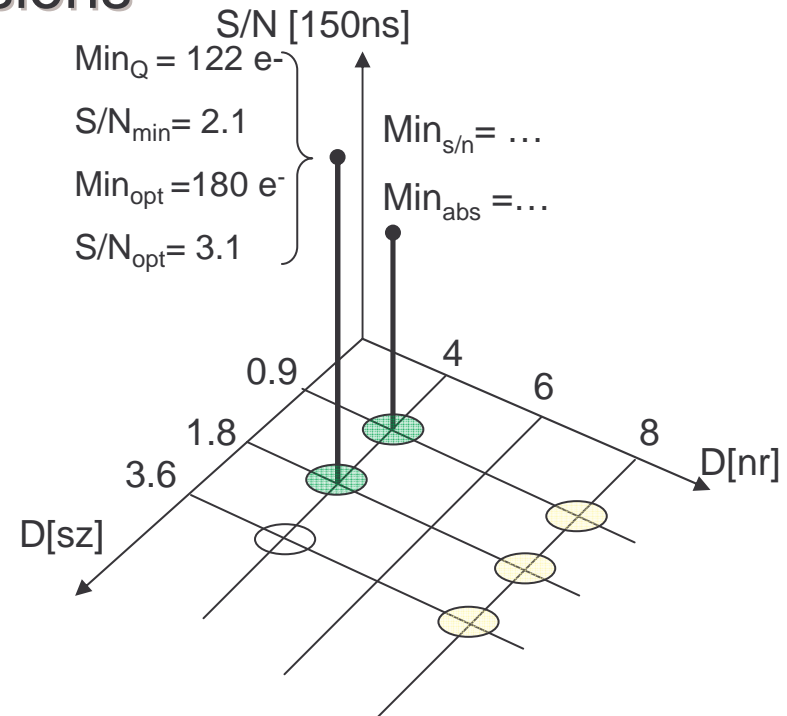
q

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## Conclusions

- Increased diodes size to  $1.8 \times 1.8 \mu\text{m}^2$  significantly improves charge collection performances.
- S/N achievable depends also on the % of area loss, but reasonable value seems to be  $\sim 4$
- Increasing the diode size will help, but it is unlikely that S/N can exceed 10



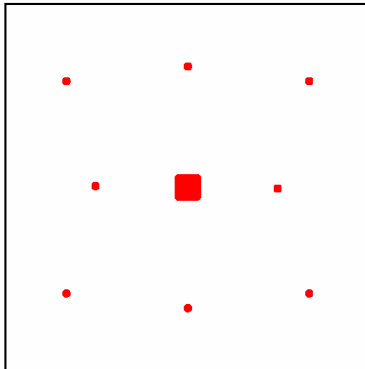
### Next step:

- Improvement in diode layout (i.e. 3.6 version and more diodes )
- To improve reliability of simulations (see above) it is strongly advisable to obtain **process information**

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- Addenda: layout coordinates
- 8 diodes coordinates:



	10.45;42. 2		39.55;42. 2	
		25;37.65		
8.95;25				41.05;25
		25;12.35		
	10.45;7.9		39.55;7.9	